

SUSS DSM8 Gen2 | DSM200 Gen2 ALIGNMENT METROLOGY FOR R&D AND HIGH-VOLUME PRODUCTION





SUSS DSM8 Gen2 | DSM200 Gen2 ALIGNMENT METROLOGY FOR R&D AND HIGH-VOLUME PRODUCTION

The SUSS DSM offers front-to-back side measurements for a broad range of applications and substrates. Results specify shift, rotation and run-out components of the offset vector. The system requires a remarkably small footprint and by that low cost of ownership. At the same time, it provides reliable and extremely accurate metrology for double-sided alignment and exposure applications, which are frequently used in the manufacturing of MEMS devices, power semiconductors and optoelectronics.

ACCURATE METROLOGY FOR DOUBLE-SIDED SUBSTRATES

SUSS MicroTec has more than 40 years of experience in double-side lithography processes. The processing of double-sided substrates requires accurate measurement to verify front-to-back side alignment. The stand-alone SUSS DSM8 recipe-based system automatically measures and calibrates itself, with manual substrate loading and unloading. This ensures high performance independent of operator skills. The fully automated SUSS DSM200 also features a robotic substrate handling system. In addition, customized handling options are available, including unique measurement chucks. Optional IR illumination enables through-silicon measurement capability.

PRECISE DUAL MICROSCOPE METROLOGY

Using a single microscope and looking through a substrate suffers the systematic offsets due to light diffraction and mechanical tolerances. SUSS DSM eliminates this by using double microscope technology to look at alignment features directly and without movement. This system also incorporates Cognex PatMax[®] image analysis software that delivers optimum precision with industry-proven stability.



HIGHLIGHTS

- + \leq 0.2 µm measurement accuracy
- + Double-side or single-side alignment measurement
- + Optional IR illumination
- + High throughput and small footprint deliver low cost of ownership
- + Customized substrate handling solutions available

ACCURACY VIA TIS COMPENSATION

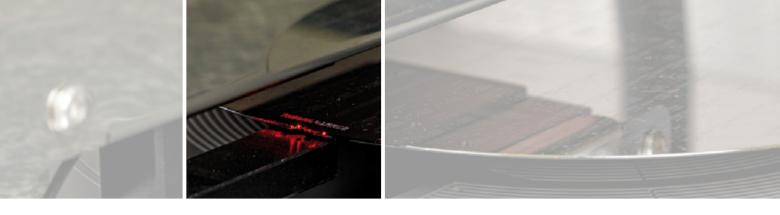
Eliminating mechanical tool induced shift (TIS) is required for optimum measurement accuracy. The SUSS DSM achieves this by comparing the measurement result of the substrate at 0° with the result at 180°. Image registration of the rotated target images, and accurate offset calculation is performed with the capabilities of Cognex PatMax[®].



SUSS DSM8 Gen2 | DSM200 Gen2 MEASUREMENT MODES

| STANDARD | | |
|---|--|---|
| Front-side to front-side measurement | Target A & Target B - Imaged via top-side microscope - Reflected visible wavelength illumination | |
| Back-side to back-side measurement | Target A & Target B - Imaged via bottom-side microscope - Reflected visible wavelength illumination | |
| Front-side to back-side measurement | Target A - Imaged via top-side microscope - Reflected visible wavelength illumination | Target B - Imaged via bottom-side microscope - Reflected visible wavelength illumination |
| INFRARED (OPTIONAL) | | |
| Front-side to interface measurement | Target A - Imaged via top-side microscope - Reflected visible wavelength illumination | Target B - Imaged via bottom-side microscope - Infrared transmission illumination |
| Back-side to interface measurement | Target A - Imaged via bottom-side microscope - Reflected visible wavelength illumination | Target B - Imaged via bottom-side microscope - Infrared transmission illumination |
| Interface to interface measurement | Target A & Target B - Imaged via bottom-side microscope - Infrared transmission illumination | |

Data, design and specification depend on individual process conditions and can vary according to equipment configurations. Not all specifications may be valid simultaneously. Illustrations, photos and specifications in this brochure are not legally binding. SUSS MicroTec reserves the right to change machine specifications without prior notice.



SUSS DSM8 Gen2 | DSM200 Gen2 TECHNICAL DATA

| WAFER/SUBSTRATE | | |
|---------------------------|---|-----------------|
| Wafer / Substrate size | Wafers up to 200mm Pieces and other substrates upon request | |
| Wafer/Substrate thickness | \leq 10 mm | |
| Type of handling system | DSM8 – Manual DSM200 – Automatic with robotic handler | |
| MEASUREMENT | | |
| | Visible Light | Infra Red |
| Accuracy (3 σ) | $\leq 0.2\mu m$ | $\leq 0.3\mu m$ |
| Repeatability (3 σ) | ≤ 0.15 µm | $\leq 0.2\mu m$ |
| Throughput | \leq 42 WPH | \leq 35 WPH |
| TIS compensation | 0° and 180° result comparison | |
| OPTICS | | |
| Microscopes | Top- and bottom-side microscopes with high and low magnification options | |
| Focus Drive | Motorized movement with available autofocus | |
| Objectives | 5x, 10x | |
| Depth of Focus | 5x objective – 8μm - 29μm 10x objective – 6μm - 11μm | |
| Cameras | 1/2"IT CCD, 640×48 | 30 pixel |
| | | |

OPTIONS

Edge grip substrate handling SECS II/GEM for DSM200 Gen2 Wafer ID reader Ergo loading cassette station for DSM200 Gen2

| UTILITIES | | |
|------------------------|---|--|
| CDA | > 0.6 MPa. Consumption 1.0 m ³ /h | |
| Vacuum | ≤ 0.02 MPa | |
| Electrical Power | 200 - 240 VAC, 50 / 60 Hz, 1 kW | |
| PHYSICAL DIMENSIONS | | |
| Width x Depth x Height | DSM8 – 728 x 1220 x 1732 mm DSM200 – 1430 x 1220 x 1732 mm | |
| Weight | DSM8 – 560 kg DSM200 – 760 kg | |

Data, design and specification depend on individual process conditions and can vary according to equipment configurations. Not all specifications may be valid simultaneously. Illustrations, photos and specifications in this brochure are not legally binding. SUSS MicroTec reserves the right to change machine specifications without prior notice.



Visit www.suss.com/locations for your nearest SUSS representative or contact us: SÜSS MicroTec SE +49 89 32007-0 · info@suss.com

WWW.SUSS.COM

